74AUP1G373-Q100

Low-power D-type transparent latch; 3-state

Rev. 2 — 27 March 2020

Product data sheet

1. General description

The 74AUP1G373-Q100 provides the single D-type transparent latch with 3-state output. While the latch-enable (LE) input is high, the Q output follows the data (D) input. When pin LE is LOW, the latch stores the information that was present at the D-input one set-up time preceding the HIGH-to-LOW transition of pin LE. When pin \overline{OE} is LOW, the contents of the latch is available at the (Q) output. When pin \overline{OE} is HIGH, the output goes to the high-impedance OFF-state. Operation of input pin \overline{OE} does not affect the state of the latch. Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V. This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 0.8 V to 3.6 V
- · High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - MIL-STD-883, method 3015 Class 3A. Exceeds 5000 V
 - HBM JESD22-A114F Class 3A. Exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- · Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation



3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G373GW-Q100	-40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363

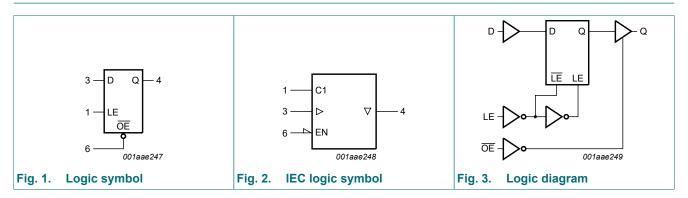
4. Marking

Table 2. Marking

Type number	Marking code [1]
74AUP1G373GW-Q100	aW

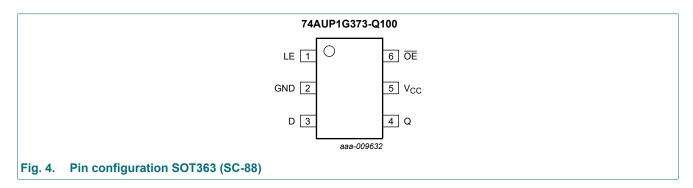
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description			
LE	1	latch enable input (active HIGH)			
GND	2	ground (0 V)			
D	3	data input			
Q	4	latch output			
V _{CC}	5	supply voltage			
ŌĒ	6	output enable input (active LOW)			

7. Functional description

Table 4. Function table

H = HIGH voltage level; h = HIGH voltage level one setup time prior to the HIGH-to-LOW LE transition;

L = LOW voltage level; I = LOW voltage level one setup time prior to the HIGH-to-LOW LE transition;

X = Don't care; Z = high-impedance OFF-state.

Operating modes	Input			Internal latch	Output
	OE	LE	D		Q
Enable and read register (transparent mode)	L	Н	L	L	L
	L	Н	Н	Н	Н
Latch and read register	L	L	I	L	L
	L	L	h	Н	Н
Latch register and disable outputs	Н	Х	Х	X	Z

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 \text{ V to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}$ [2]	-	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] For SOT363 (SC-88) package: Ptot derates linearly with 3.7 mW/K above 83 °C.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	-	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{IH}	HIGH-level input	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-		V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-		V	
	voltage	V _{CC} = 0.9 V to 1.95 V	-		V	
V _{IL} L _V V _{OL} L _V		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
•	voltage	I _O = -20 μ A; V _{CC} = 0.8 V to 3.6 V V _{CC} - 0.1 -		-	V	
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
			-	V		
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	$I_O = 20 \mu A; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	× V _{CC}	V	
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μA
l _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μΑ
l _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$	-	-	±0.2	μΑ
ΔI _{OFF}	additional power-off leakage current	V_{I} or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$ to 0.2 V	-	-	±0.2	μΑ
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.5	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μΑ
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V_I = GND or V_{CC}	-	0.8	-	pF
Co	output capacitance	output enabled; V _O = GND; V _{CC} = 0 V	-	1.7	-	pF
		output disabled; V_{CC} = 0 V to 3.6 V; V_{O} = GND or V_{CC}	-	1.5	-	pF
T _{amb} = -4	40 °C to +85 °C					
V _{IH}	HIGH-level input	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V_{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	$I_O = -20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	V _{CC} - 0.1	-	-	V
		$I_O = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.7 \times V_{CC}$	-	-	V
		$I_O = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.03	-	-	V
		$I_O = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.30	-	-	V
		$I_O = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
		$I_O = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	V
		$I_O = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
		$I_O = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
V_{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	$I_O = 20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		$I_O = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		$I_O = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.33	V
		$I_O = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.45	V
		$I_O = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.33	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.45	V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OZ}	OFF-state output current	V _I = V _{IH} or V _{IL} ; V _O = 0 V to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.5	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μA
ΔI_{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.9	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μA
T _{amb} = -4	40 °C to +125 °C				'	
V_{IH}	HIGH-level input	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V_{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
I _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μΑ
ΔI_{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.75	μΑ
I _{CC}	supply current	$V_1 = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μΑ
ΔI _{CC}	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	75	μΑ

^[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
$C_L = 5 p$	F									
t _{pd}	propagation	D to Q; see <u>Fig. 5</u> [2]								
	delay	V _{CC} = 0.8 V	-	21.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	6.6	13.5	2.6	13.8	2.6	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.4	4.6	7.8	2.1	8.3	2.1	9.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.7	6.2	1.6	6.7	1.6	7.3	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	2.9	4.1	1.5	4.5	1.5	4.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.5	2.5	3.5	1.2	4.0	1.2	4.5	ns
		LE to Q; see Fig. 6 [2]								
		V _{CC} = 0.8 V	-	20.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.7	6.2	13.6	2.5	14.0	2.5	15.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.4	7.6	2.0	8.5	2.0	9.3	ns
		V _{CC} = 1.65 V to 1.95 V	1.8	3.5	5.8	1.5	6.7	1.5	7.3	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	2.6	4.0	1.3	4.4	1.3	4.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	2.2	3.3	1.1	3.8	1.1	4.2	ns
t _{en}	enable time	OE to Q; see Fig. 8 [3]								
		V _{CC} = 0.8 V	-	17.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	5.1	9.2	3.0	9.2	3.0	10.1	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	3.8	5.8	2.4	6.1	2.4	6.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	3.3	4.8	2.0	5.0	2.0	5.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	2.7	3.8	1.8	4.0	1.8	4.4	ns
		V _{CC} = 3.0 V to 3.6 V	1.9	2.5	3.4	1.8	3.6	1.8	4.0	ns

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	_	°C to 5 °C	Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
t _{dis}	disable time	OE to Q; see Fig. 8 [4]								
		V _{CC} = 0.8 V	-	9.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.9	4.2	7.5	2.8	7.9	2.8	8.7	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	3.2	4.9	2.1	5.3	2.1	5.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	3.0	4.4	2.1	4.9	2.1	5.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	2.2	3.1	1.5	3.4	1.5	3.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.9	2.6	3.3	1.8	3.6	1.8	4.0	ns
C _L = 10	pF						,		'	
t _{pd}	propagation	D to Q; see <u>Fig. 5</u> [2]								
	delay	V _{CC} = 0.8 V	-	24.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.0	7.5	15.3	2.7	15.9	2.7	17.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	5.3	9.0	2.2	9.4	2.2	10.3	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	4.3	6.9	2.1	7.3	2.1	8.0	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.5	4.8	1.8	5.3	1.8	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	3.1	4.2	1.7	4.6	1.7	5.1	ns
		LE to Q; see Fig. 6 [2]								
		V _{CC} = 0.8 V	-	23.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.9	7.1	15.4	2.7	16.1	2.7	17.7	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	5.0	8.8	2.1	9.5	2.1	10.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.1	6.6	2.0	7.3	2.0	8.1	ns
		V _{CC} = 2.3 V to 2.7 V	1.9	3.1	4.7	1.6	5.2	1.6	5.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.8	4.0	1.4	4.4	1.4	4.9	ns
t _{en}	enable time	OE to Q; see Fig. 8 [3]								
		V _{CC} = 0.8 V	-	21.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.7	6.0	10.6	3.4	10.6	3.4	11.7	ns
		V _{CC} = 1.4 V to 1.6 V	3.1	4.5	6.7	2.8	7.0	2.8	7.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.7	3.9	5.5	2.5	5.8	2.5	6.4	ns
		V _{CC} = 2.3 V to 2.7 V	2.4	3.3	4.5	2.2	4.7	2.2	5.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.3	3.1	4.1	2.2	4.3	2.2	4.7	ns
t _{dis}	disable time	OE to Q; see Fig. 8 [4]								
		V _{CC} = 0.8 V	-	11.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.9	5.3	8.7	3.8	9.2	3.8	10.1	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	4.1	5.8	2.9	6.2	2.9	6.8	ns
		V _{CC} = 1.65 V to 1.95 V	3.2	4.2	5.7	3.1	6.0	3.1	6.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	3.0	4.0	2.2	4.3	2.2	4.7	ns
		V _{CC} = 3.0 V to 3.6 V	3.0	3.8	4.7	2.9	5.0	2.9	5.5	ns

Symbol	Parameter	meter Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min Max		Min	Max	
C _L = 15	pF									
t _{pd}	propagation	D to Q; see <u>Fig. 5</u> [2]								
	delay	V _{CC} = 0.8 V	-	27.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.5	8.3	16.9	3.2	17.5	3.2	19.2	ns
		V _{CC} = 1.4 V to 1.6 V	3.1	5.9	9.6	2.7	10.5	2.7	11.6	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	4.8	7.6	2.2	8.5	2.2	9.3	ns
		V _{CC} = 2.3 V to 2.7 V	2.5	3.9	5.5	2.2	5.9	2.2	6.5	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	3.6	4.9	1.8	5.5	1.8	6.0	ns
		LE to Q; see Fig. 6 [2]								
		V _{CC} = 0.8 V	-	26.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.3	7.9	17.3	3.0	18.0	3.0	19.8	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.6	9.7	2.5	10.7	2.5	11.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	4.6	7.4	2.2	8.3	2.2	9.1	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	3.6	5.3	2.0	5.9	2.0	6.4	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.2	4.6	1.8	5.1	1.8	5.6	ns
t _{en}	enable time	OE to Q; see Fig. 8 [3]								
		V _{CC} = 0.8 V	-	24.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.1	6.8	12.1	3.8	12.1	3.8	13.3	ns
		V _{CC} = 1.4 V to 1.6 V	3.5	5.1	7.5	3.2	7.9	3.2	8.7	ns
		V _{CC} = 1.65 V to 1.95 V	3.1	4.4	6.1	2.8	6.5	2.8	7.2	ns
		V _{CC} = 2.3 V to 2.7 V	2.8	3.7	5.0	2.5	5.3	2.5	5.8	ns
		V _{CC} = 3.0 V to 3.6 V	2.6	3.5	4.7	2.5	4.9	2.5	5.4	ns
t _{dis}	disable time	OE to Q; see Fig. 8 [4]								
		V _{CC} = 0.8 V	-	13.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.9	6.5	9.8	4.8	10.4	4.8	11.4	ns
		V _{CC} = 1.4 V to 1.6 V	3.9	5.0	6.8	3.8	7.3	3.8	8.0	ns
		V _{CC} = 1.65 V to 1.95 V	4.2	5.3	6.9	4.1	7.3	4.1	8.0	ns
		V _{CC} = 2.3 V to 2.7 V	3.0	3.8	4.8	2.9	5.1	2.9	5.6	ns
		V _{CC} = 3.0 V to 3.6 V	4.1	5.0	6.1	4.0	6.4	4.0	7.0	ns

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	-
C _L = 30	pF					•			•	
t _{pd}	propagation	D to Q; see <u>Fig. 5</u> [2]								
	delay	V _{CC} = 0.8 V	-	35.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.0	10.6	22.1	3.7	23.3	3.7	25.6	ns
		V _{CC} = 1.4 V to 1.6 V	3.6	7.5	12.3	3.5	13.6	3.5	15.0	ns
		V _{CC} = 1.65 V to 1.95 V	3.5	6.2	9.5	3.2	10.5	3.2	11.5	ns
		V _{CC} = 2.3 V to 2.7 V	3.3	5.1	6.9	2.9	7.6	2.9	8.3	ns
		V _{CC} = 3.0 V to 3.6 V	3.0	4.7	6.4	2.9	7.2	2.9	7.9	ns
		LE to Q; see Fig. 6 [2]								
		V _{CC} = 0.8 V	-	34.8	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.9	10.2	22.2	3.7	23.5	3.7	25.9	ns
		V _{CC} = 1.4 V to 1.6 V	3.5	7.2	12.4	3.4	13.7	3.4	15.1	ns
		V _{CC} = 1.65 V to 1.95 V	3.3	5.9	9.5	3.0	10.5	3.0	11.6	ns
		V _{CC} = 2.3 V to 2.7 V	3.1	4.8	6.8	2.7	7.5	2.7	8.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.9	4.4	6.1	2.6	7.0	2.6	7.7	ns
t _{en}	enable time	OE to Q; see Fig. 8 [3]								
		V _{CC} = 0.8 V	-	34.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	5.5	9.1	16.2	4.9	16.2	4.9	17.8	ns
		V _{CC} = 1.4 V to 1.6 V	4.6	6.7	9.9	4.2	10.5	4.2	11.6	ns
		V _{CC} = 1.65 V to 1.95 V	4.2	5.7	7.9	3.7	8.6	3.7	9.5	ns
		V _{CC} = 2.3 V to 2.7 V	3.6	4.9	6.4	3.4	6.9	3.4	7.6	ns
		V _{CC} = 3.0 V to 3.6 V	3.4	4.7	6.1	3.3	6.5	3.3	7.2	ns
t _{dis}	disable time	OE to Q; see Fig. 8 [4]								
		V _{CC} = 0.8 V	-	19.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	8.0	9.9	13.7	7.9	14.5	7.9	16.0	ns
		V _{CC} = 1.4 V to 1.6 V	6.3	7.7	9.7	6.2	10.5	6.2	11.6	ns
		V _{CC} = 1.65 V to 1.95 V	7.3	8.7	10.6	7.2	11.3	7.2	12.4	ns
		V _{CC} = 2.3 V to 2.7 V	5.2	6.2	7.5	5.1	7.8	5.1	8.6	ns
		V _{CC} = 3.0 V to 3.6 V	7.5	8.8	10.2	7.4	10.5	7.4	11.6	ns
C _L = 5 p	F, 10 pF, 15 p	F and 30 pF						•	•	
t _W	pulse width	LE HIGH; see Fig. 6								
		V _{CC} = 0.8 V	-	4.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	0.7	-	2.1	-	2.1	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	0.5	-	1.3	-	1.3	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.4	-	1.0	-	1.0	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.3	-	0.8	-	8.0	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.2	-	0.8	-	0.8	-	ns

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
t _{su(H)}	set-up time	D to LE; see Fig. 7								
	HIGH	V _{CC} = 0.8 V	-	4.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	0.9	-	2.2	-	2.2	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	0.6	-	1.4	-	1.4	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.4	-	1.0	-	1.0	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0	-	0.6	-	0.6	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	-0.1	-	0.4	-	0.4	-	ns
t _{su(L)}	set-up time	D to LE; see Fig. 7								
	LOW	V _{CC} = 0.8 V	-	4.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	1.2	-	2.7	-	2.7	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	0.7	-	1.5	-	1.5	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.6	-	1.2	-	1.2	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.4	-	0.9	-	0.9	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.3	-	0.7	-	0.7	-	ns
t _h	hold time	D to LE HIGH or LOW; see Fig. 7								
		V _{CC} = 0.8 V	-	-4.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	-0.9	-	-0.1	-	-0.1	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	-0.6	-	-0.1	-	-0.1	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	-0.4	-	0	-	0	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	-0.2	-	0.2	-	0.2	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	-0.1	-	0.3	-	0.3	-	ns
C _{PD}	power dissipation	f _i = 1 MHz; V _I = GND to V _{CC} ; [5] [6] output enabled								
	capacitance	V _{CC} = 0.8 V	-	2.0	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.0	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	2.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	2.1	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	2.4	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	2.8	-	-	-	-	-	pF

- All typical values are measured at nominal V_{CC}.
- t_{pd} is the same as t_{PLH} and $t_{\text{PHL}}.$
- t_{en} is the same as t_{PZH} and t_{PZL}.
- [4] t_{dis} is the same as t_{PHZ} and t_{PLZ}.
 [5] All specified values are the average typical values over all stated loads.
 [6] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 P_D = C_{PD} × V_{CC}² × f_i × N + Σ(C_L × V_{CC}² × f_o) where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs;

N = number of inputs switching.

11.1. Waveforms

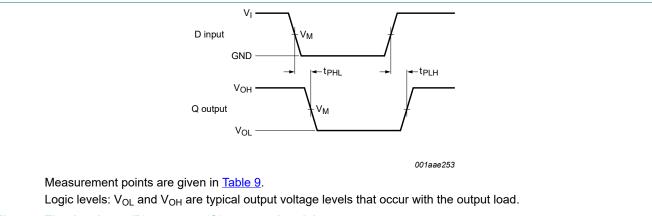


Fig. 5. The data input (D) to output (Q) propagation delays

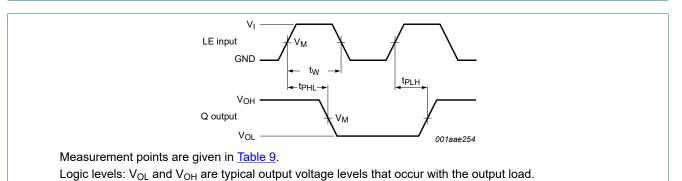


Fig. 6. The latch enable input (LE) to output (Q) propagation delays, the latch enable input (LE) pulse width

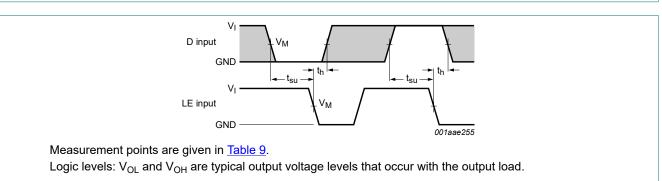
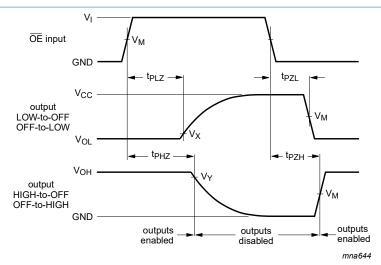


Fig. 7. Data set-up and hold times for the D input to the LE input

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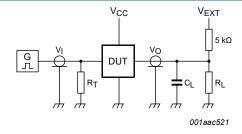
Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 8. Turn-on and turn-off times

Table 9. Measurement points

Supply voltage	Input			Output				
V _{CC}	V _M	VI	$t_r = t_f$	V _M	V _X	V _Y		
0.8 V to 1.6 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.1 V	V _{OH} - 0.1 V		
1.65 V to 2.7 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V		
3.0 V to 3.6 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V		



Test data is given in Table 10.

Definitions for test circuit:

 R_{I} = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig. 9. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Load		V _{EXT}		
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times R_L = 5 k Ω .

For measuring propagation delays, setup and hold times and pulse width R_L = 1 $\mbox{M}\Omega.$

12. Package outline

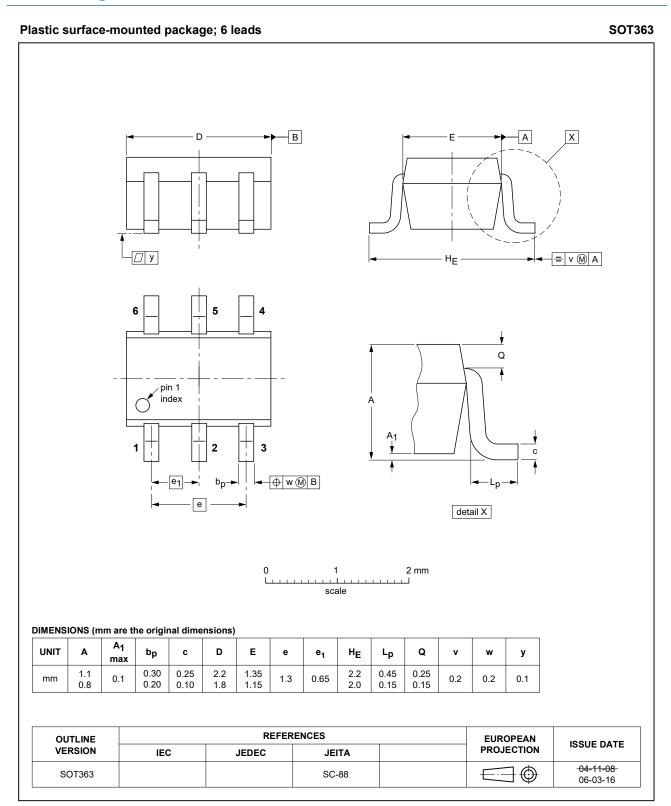


Fig. 10. Package outline SOT363 (SC-88)

13. Abbreviations

Table 11. Abbreviations

Acronym	Description
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MIL	Military
MM	Machine Model

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AUP1G373_Q100 v.2	20200327	Product data sheet	-	74AUP1G373_Q100 v.1			
Modifications:	guidelines o Legal texts l	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Table 5: Derating values for P_{tot} total power dissipation updated. 					
74AUP1G373_Q100 v.1	20140310	Product data sheet	-	-			

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Low-power D-type transparent latch; 3-state

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Product data sheet

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For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 27 March 2020

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